

isc Silicon PNP Power Transistor

2SB848

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : $V_{(BR)CEO}$ = -100V(Min)
- · Good Linearity of hFE
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

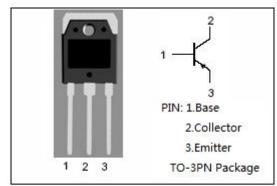
APPLICATIONS

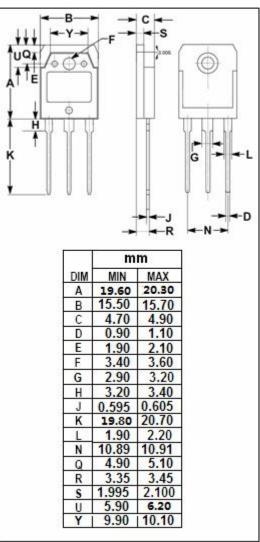


Audio frequency power amplifier applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-100	V
V _{CEO}	Collector-Emitter Voltage	-100	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-6	А
I _{CP}	Collector Current Pulse	-10	А
Pc	Collector Power Dissipation @ T _C =25℃	70	W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _(BR) CEO	Collector-Emitter Breakdown Voltage	I _C = -10mA ; I _B = 0	-100			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -0.6A			-2.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -6A ; V _{CE} = -5V			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -100V ; I _E = 0			-10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-10	μА
h _{FE}	DC Current Gain	Ic= -1A; Vc== -5V	55		160	
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f _{test} = 1.0MHz		270		pF
f⊤	Current-Gain—Bandwidth Product	I _C =-1A ; V _{CE} = -5V		10		MHz

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